

Vishay Siliconix

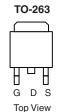
N-Channel 100-V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	r _{DS(on)} (Ω)	I _D (A)		
100	0.024 at V _{GS} = 10 V	47		
	0.027 at V _{GS} = 4.5 V	44		

FEATURES

- TrenchFET[®] Power MOSFET
- 175 °C Maximum Junction Temperature
- 100 % Rg Tested





G Q S

Ordering Information: SUM47N10-24L-E3 (Lead (Pb)-free)

N-Channel MOSFET

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ABSOLUTE MAXIMUM RATINGS T_A =	25 °C, unless othe	erwise noted			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	100	N/	
Gate-Source Voltage		V _{GS}	± 20	- V	
	T _C = 25 °C		47		
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 125 °C		27		
Pulsed Drain Current		I _{DM}	70	А	
Continuous Source Current (Diode Conduction)		۱ _S	47		
Single Pulse Avalanche Current		I _{AS}	40		
Single Pulse Avalanche Energy (Duty Cycle \leq 1 %)	L = 0.1 mH	E _{AS}	80	mJ	
Menimum Denne Dissis sties	T _C = 25 °C	P _D	136 ^b	10/	
Maximum Power Dissipation	T _A = 25 °C		3.75 ^a	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Unit	
Junction-to-Ambient	PCB Mount	R _{thJA}	40	°C/W	
Junction-to-Ambient	Free Air	TthJA	62.5		
Junction-to-Case		R _{thJC}	1.1		

Notes:

a. Surface Mounted on 1" x 1" FR4 Board.

b. See SOA curve for voltage derating.

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Parameter Symbo		Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static					<u> </u>		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	100				
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1.0		3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V			1	μΑ	
		V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 125 °C			50		
		V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 175 °C			250		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	70			А	
Drain-Source On-State Resistance ^b	r _{DS(on)}	V _{GS} = 10 V, I _D = 40 A		0.019	0.024	- Ω	
		V_{GS} = 10 V, I _D = 40 A, T _J = 125 °C			0.048		
		V_{GS} = 10 V, I _D = 40 A, T _J = 175 °C			0.060		
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.021	0.027		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 40 A		70		S	
Dynamic ^a							
Input Capacitance	C _{iss}			2400		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V, V_{DS} = 25 V, F = 1 MHz$		290			
Reverse Transfer Capacitance	C _{rss}			120			
Total Gate Charge ^c	Qg			40	60		
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 50 V, V_{GS} = 10 V, I_D = 40 A		11		nC	
Gate-Drain Charge ^c	Q _{gd}			9			
Gate Resistance	Rg	f = 1 MHz	1	2.2	3.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}			8	13		
Rise Time ^c	t _r	V_{DD} = 50 V, R_L = 1.25 Ω		40	60	ns	
Turn-Off Delay Time ^c	t _{d(off)}	$\text{I}_\text{D}\cong$ 47 A, V_GEN = 10 V, R_g = 2.5 Ω		15	25		
Fall Time ^c	t _f			80	120		
Source-Drain Diode Ratings and Cha	racteristics 7	_C = 25 °C		·	· ·		
Pulsed Current	I _{SM}				70	А	
Diode Forward Voltage ^b	V _{SD}	I _F = 40 A, V _{GS} = 0 V		1.0	1.5	V	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 47 A, di/dt = 100 A/μs		75	120	ns	

Notes:

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. Independent of operating temperature.

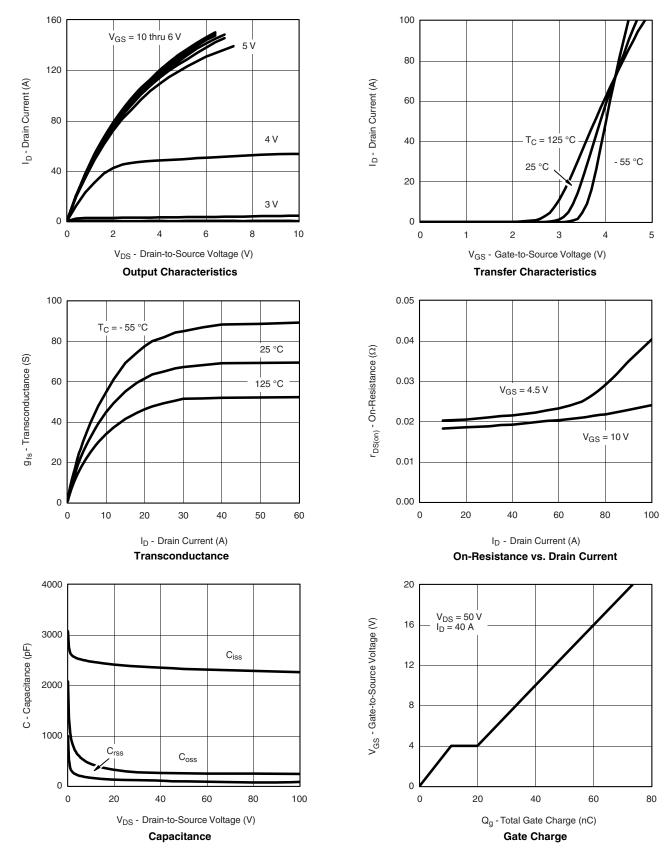
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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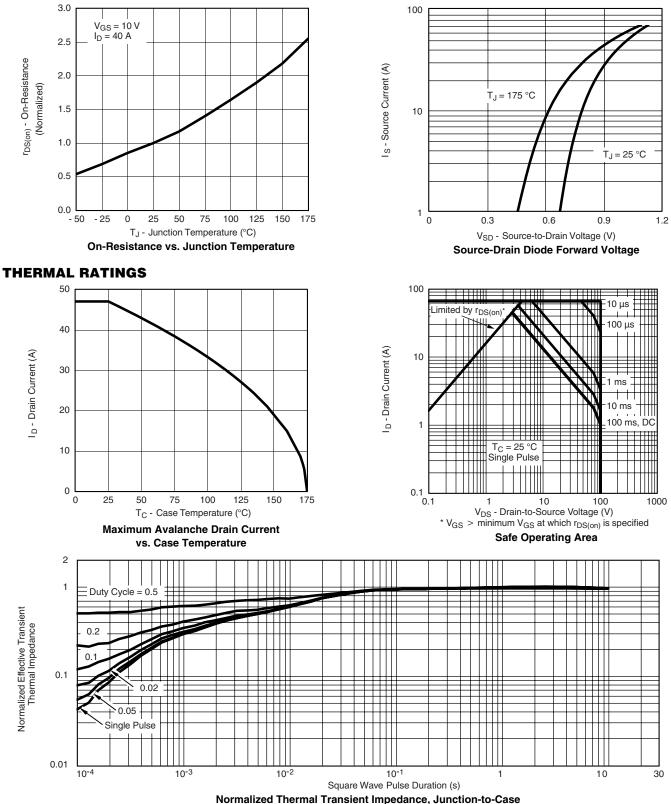




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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72827.

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